Microimmersion lens LEDs for portable photoacoustic methane sensors

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Abstract.

Microimmersion lens mid-infrared light emitting diodes (mid-IR LEDs) operating in the 3.4 μ m wavelength range, which covers the absorption bands of many important hydrocarbons (CH₄, C₃H₈...), have been studied with respect to their application in cantilever enhanced photoacoustic trace gas detection technique

Key words: IR LEDs, photoacoustic methane sensors, NDIR spectroscopy, immersion lenses

Introduction

There is a wide range of applications in which sensitive trace gas detection is needed, and both non-spectroscopic and spectroscopic methods are used for these purposes. The photoacoustic (PA) gas detection can offer high sensitivities without excessive long absorption lengths since the sensitivity is limited by the pressure increment that does not change as the gas volumes are decreased.

The highest sensitivities have been achieved so in PA systems equipped far with silicon cantilever micromachined whose displacement is measured via a Michelson-type laser interferometer. Light emitting diodes (LEDs) can offer additional benefits since LED output is easily modulated by current pulsing with frequencies up to several MHz, besides they have small size and power consumption,. Recently it has been reported that with immersion mid-IR lens LEDs and interferometric cantilever microphone the ppmlevel gas detection limits can be achieved [1]. The above LEDs were equipped with 3.5 mm wide lenses that were 10-fold wider than the LED active area of appr. 250x250 µm dimensions. Large lens dimensions provides both good outcoupling efficiency and imaging of the active area at a distance of ~ 30 mm from the LED [1]. However the image dimensions were increased with respect to the original and thus it was not possible to utilize properly all LED output power - well known problem in many instruments with entrance slid or detector elements of limited dimensions, e.g. in the PA analyzers with miniature gas cell and coherently with small entrance windows.

Formation of a chalcogenide glass drop directly onto a LED surface enable efficient radiation outcoupling from a LED since the above glass possess both high transparency and high refractive index (n=2.3-2.5) [2, 4]. The above features together with high surface tension and good adhesion to semiconductor make chalcogenide immersion lens technology attractive for analyzers with miniature gas cells and entrance windows.

In this paper we study microimmersion lens LEDs that to our understanding solve the problem, that is, provide both high extraction and collection efficiency in miniature optical systems, based on mid-IR LED technology.

Experimental details

Single heterostructures were grown by the LPE method and consisted of 350 μ m thick heavily doped n⁺-InAs (Sn) substrates with an electron concentration n=(3÷6)·10¹⁸ cm ⁻³ and two epilayers. They represented 2÷4 μ m thick n-InAs active region and 2-3 μ m thick wide-gap p-InAs_{1.x-y}Sb_xP_y (Zn) (x≈0.09, y≈0.18, p=2÷5 10¹⁷ cm ⁻³) cap layer. The obtained heterostructures were processed by a wet photolithography into ~ 400×590 μ m chips with ~ 170×170 μ m mesas with mesa depth up to 25-30 μ m, contact areas being on the same (epitaxial) chip side. Both chip contacts were connected to contact areas of a 1.8x0.9x0.4 mm semiinsulating Si-

submount by soldering at 180°C. Finally the Si submounts with LED chips were soldered onto a TO-18. Chalcogenide glass lens was formed directly onto free LED surface (InAs substrate) as shown in Fig.1.

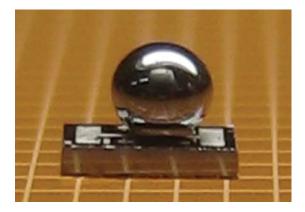


Fig. 1. Photo of microimmersion lens LED onto 1.8x0.9x0.4 mm Si submount. Grid cells are of 0.5x0.5 mm dimensions.

X-Y movable stage was used for distribution of radiation along the plane with area up to 20x20 mm placed at distance *L* of 0, 5 and 10 mm from the LED (see Fig.2). Home made InAs flip chip photodiode (PD) with 210x210 μ m active area was used for intensity registration performed at LED pulsing at 500 Hz with 1:1 duty cycle). "IR images" or intensity "maps" consisted of 40x40 (step 500 μ m) pixels, no corrections accounted for variation of incident angle θ have been made.

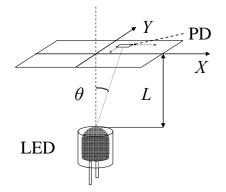


Fig. 2. Schematic of the far field measurements with the X-Y scanning system

Results and discussion

Fig.3 presents dependence of relative output power on lens dimensions (lens pedestal height H) in microimmersion lens LEDs with a fixed value of surface radii (lateral dimensions) -1.1mm that is currently though to be optimal for applications in mind. It follows from Fig.3 that the highest extraction efficiency (best power) is achieved at zero pedestal height H that corresponds to a hemispherical lens where all rays coming from the active area "hit" surface at nearly zero incident angle.

Unfortunately hemispherical lens provides the worst beam divergence and thus the collection efficiency for a concave concentrator optical scheme falls down to a minimum as seen from Fig.4.

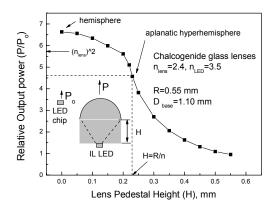


Fig. 3. Dependence of relative output power on lens dimensions (pedestal height H). P_0 and P are the output power of plane chip and chip immersed into a chalcogenide glass lens respectively.

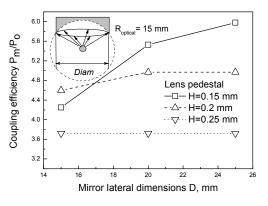


Fig. 4. Optical coupling efficiency for microimmersion lens LED – spherical mirror pair vs mirror diameter for mirror radii fixed at 15 mm.

This is not a surprise that the increase of the pedestal height H is followed by a collection efficiency enhancement (see Fig.4) as lens is attaining ability to concentrate radiation into a spatially narrow beam with limited divergence. However, the extraction efficiency (Fig.3) is not 100% for the case as only limited number of incident angles are smaller than the angle of total internal reflection ($\theta_{cr.}$ = 24.5 deg.). provide that Conditions both adequate outcoupling and coupling efficiency are thought to be such that H=R/n, where n - is the lens refractive index (n=2.4). These "aplanatic hyperhemisphere" lenses with H=R/n are well known in photodiode [4, 5, 6] and LED [2, 4, 7] technology using Si or Ge lenses. In our case the condition H=R/n was hardly acheived as lens pedestal depends on radii (or lens mass). Nevertheless we were able to fabricate nearly identical immersion lens LED with quite nice average power of 120 μW (at 100 mA) and typical dependence of beam amplitude, FWHM presented in Fig.5. FWHM, β and amplitudes (A) listed in Fig.5 were calculated from Gauss function approximation of the experimental data (line scan from beam center). As seen from Fig.5 microimmersion lens LED beam FWHM linearly increases as the distance L is increased, the FWHM magnitude is smaller than expected for the plain LED chip. The latter "Lambertian" LED $(A \sim (L/sqrt(L^2+(x)^2))^4)$ provides FWHM_{Lamb} = 13 mm against FWHM = 3.7 mm for microimmersion LEDs at L=10 mm.

The collimating effect in our LEDs and high coupling efficiency in mirror based optical schemes are evident – there is minor change of the A* β^2 parameter accounting for the integral power that can be collected at a distance L. The latter was confirmed by the Zemax analysis of the LED beams collected by spherical mirror and by experiments. Nearly 74% collection efficiency was achieved when LED was placed at a distance of 12 mm from gold plated mirror whose surface radius was 12.0 mm (the focus length 6.0 mm), the diameter 12.0 mm .

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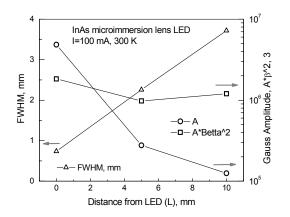


Fig. 5. Beam characteristics vs distance from LED

Conclusions

Microimmersion lens technology provides several benefits for the optical instrumentation based on mid-IR components including small emitting size and ourtput power compared to conventional LED with Si lenses [8]. Low cost, small size of the miroimmerison lens LED are key features for portable instruments, e.g. based on PA spectroscopy. In near future experimental verification of applicability of the above technology to PA gas analyzer incorporating micromachined silicon cantilever whose displacement is measured via a novel laser interferometer will be made.

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